VS-10ETF02FP-M3, VS-10ETF04FP-M3, VS-10ETF06FP-M3

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Vishay Semiconductors

Fast Soft Recovery Rectifier Diode, 10 A



2L TO-220 FullPAK

PRIMARY CHARACTERISTICS				
I _{F(AV)}	10 A			
V _R	200 V, 400 V, 600 V			
V _F at I _F	1.2 V			
I _{FSM}	160 A			
t _{rr}	50 ns			
T _J max.	150 °C			
Snap factor	0.5			
Package	2L TO-220 FullPAK			
Circuit configuration	Single			

FEATURES

- Glass passivated pellet chip junction
- 150 °C max. operation junction temperature
- Designed and qualified according to JEDEC[®]-JESD 47



HALOGEN

FREE

- Fully isolated package (V_{INS} = 2500 V_{RMS})
- UL pending
- · Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

APPLICATIONS

These devices are intended for use in output rectification and freewheeling in inverters, choppers and converters as well as in input rectification where severe restrictions on conducted EMI should be met.

DESCRIPTION

The VS-10ETF0..FP... fast soft recovery rectifier series has been optimized for combined short reverse recovery time and low forward voltage drop.

The glass passivation ensures stable reliable operation in the most severe temperature and power cycling conditions.

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL	CHARACTERISTICS	VALUES	UNITS				
V _{RRM}		200 to 600	V				
I _{F(AV)}	Sinusoidal waveform	10	А				
I _{FSM}		160	~				
t _{rr}	1 A, 100 A/µs	50	ns				
V _F	10 A, T _J = 25 °C	1.2	V				
TJ		-40 to +150	°C				

VOLTAGE RATINGS							
PART NUMBER	V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	AT 150 °C mA				
VS-10ETF02FP-M3	200	300					
VS-10ETF04FP-M3	400	500	3				
VS-10ETF06FP-M3	600	700					

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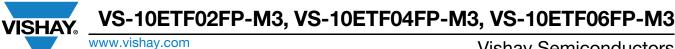
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ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum average forward current	I _{F(AV)}	T_{C} = 98 °C, 180° conduction half sine wave	10			
Maximum peak one cycle	1	10 ms sine pulse, rated V_{RRM} applied	150	A		
non-repetitive surge current	IFSM	10 ms sine pulse, no voltage reapplied	160			
Maximum I ² t for fusing I ² t		10 ms sine pulse, rated V _{RRM} applied	112.5	A ² s		
Maximum I ² t for fusing	1-1	10 ms sine pulse, no voltage reapplied	160	— A ² S		
Maximum I ² √t for fusing	l²√t	t = 0.1 to 10 ms, no voltage reapplied	1600	A²√s		

ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS VALUES			UNITS	
Maximum forward voltage drop	V _{FM}	10 A, T _J = 25 °C		1.2	V	
Forward slope resistance	r _t	T _{.1} = 150 °C	23.5	mΩ		
Threshold voltage	V _{F(TO)}	1j = 150°C	0.85	V		
Maximum reverse leakage current		T _J = 25 °C	V - Poted V	0.1	mA	
Maximum reverse leakage current	IRM	T _J = 150 °C	$V_{R} = Rated V_{RRM}$	3.0	ША	

RECOVERY CHARACTERISTICS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	· •		
Reverse recovery time	t _{rr}	In at 10 Au	200	ns	I _{FM}		
Reverse recovery current	I _{rr}	l _F at 10 A _{pk} 25 A/µs	2.75	A			
Reverse recovery charge	Q _{rr}	25 °C	0.32	μC			
Snap factor	S		0.6				

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	SYMBOL TEST CONDITIONS		UNITS	
Maximum junction and storage temperature range		T _J , T _{Stg}		-40 to +150	°C	
Maximum thermal resistance junction to case		R _{thJC}	DC operation	2.5		
Maximum thermal resistance junction to ambient		R _{thJA}		62	°C/W	
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth, and greased	0.5		
Approximate weight				2	g	
Approximate weight				0.07	oz.	
Mounting torque minimum maximum				6 (5)	kgf ⋅ cm	
				12 (10)	(lbf ⋅ in)	
Marking device			Case style 2L TO-220 FullPAK	10ETF02FP 10ETF04FP 10ETF06FP		



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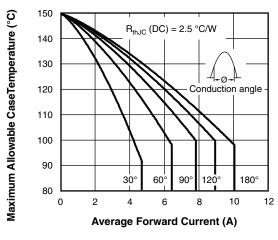


Fig. 1 - Current Rating Characteristics

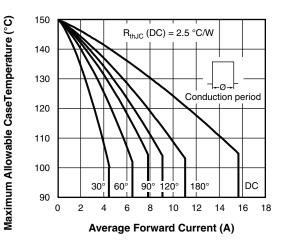


Fig. 2 - Current Rating Characteristics

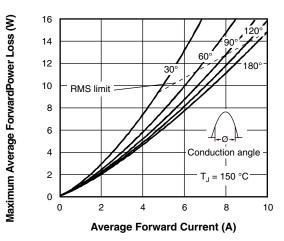
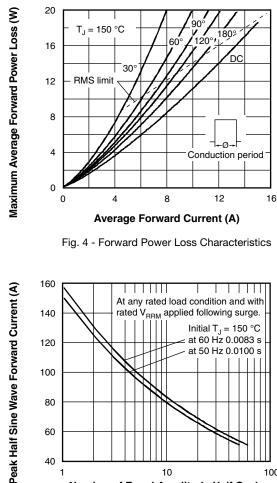
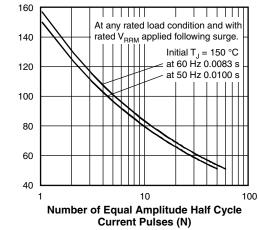


Fig. 3 - Forward Power Loss Characteristics







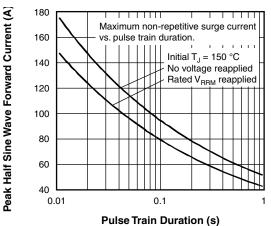


Fig. 6 - Maximum Non-Repetitive Surge Current

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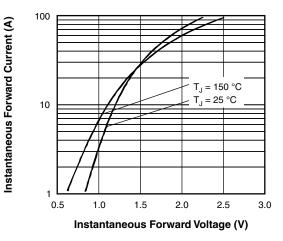


Fig. 7 - Forward Voltage Drop Characteristics

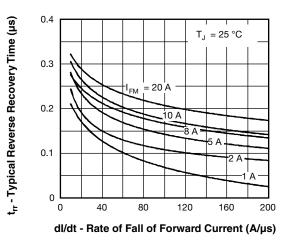


Fig. 8 - Recovery Time Characteristics, $T_J = 25 \ ^{\circ}C$

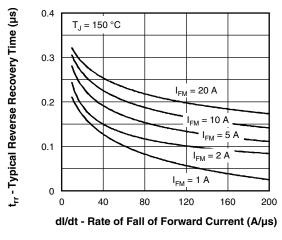


Fig. 9 - Recovery Time Characteristics, $T_J = 150 \ ^\circ C$

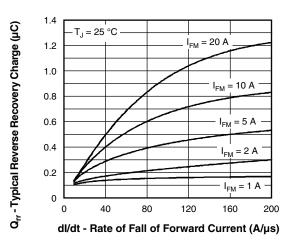


Fig. 10 - Recovery Charge Characteristics, T_J = 25 °C

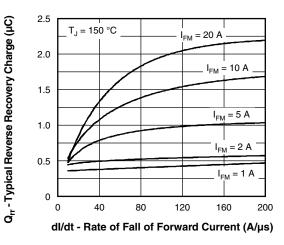
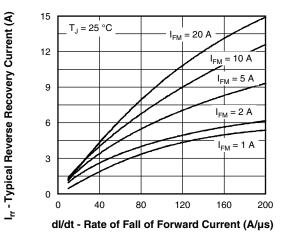
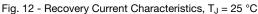


Fig. 11 - Recovery Charge Characteristics, T_J = 150 °C





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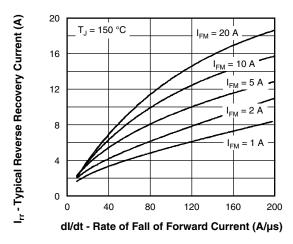


Fig. 13 - Recovery Current Characteristics, T_J = 150 °C

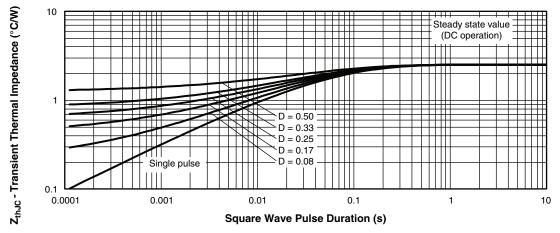


Fig. 14 - Thermal Impedance Z_{thJC} Characteristics

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ORDERING INFORMATION TABLE

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Device code	VS-	10	E	т	F	06	FP	-МЗ
	(1)	(2)	(3)	(4)	(5)	(6)	(7)	(8)
	1 -	- Visł	nav Sen	niconduo	ctors pro	oduct		
	2 -		-	ng (10 =	•			
	3 -	- Circ	uit conf	iguratio	า:			
		E =	single o	liode				
	4 -	- Pac	kage:					
		T =	TO-220)				
	5 -	• Тур	e of silio	con:				
		F =	fast sof	t recove	ry rectif	ier	02 = 2	200 V
	6 -	· Volt	age coo	de x 100	= V _{RRN}	1		400 V
	7 -	· Full	PAK				06 = 6	600 V
	8 -	- Env	rironmer	ntal digit	:			
		-M3	3 = halo	gen-free	e, RoHS	-compli	ant, and	d termir

ORDERING INFORMATION (Example)							
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION				
VS-10ETF02FP-M3	50	1000	Antistatic plastic tubes				
VS-10ETF04FP-M3	50	1000	Antistatic plastic tubes				
VS-10ETF06FP-M3	50	1000	Antistatic plastic tubes				

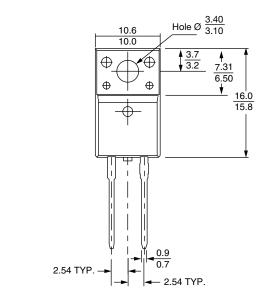
LINKS TO RELATED DOCUMENTS					
Dimensions www.vishay.com/doc?96157					
Part marking information	www.vishay.com/doc?95392				

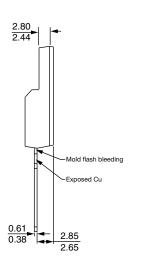


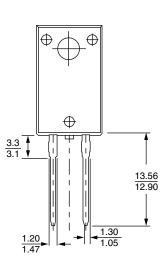
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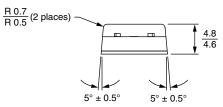
DIMENSIONS in millimeters







Bottom view





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